

# High-Density, ±5V Capable DPDT Analog Switches

#### **General Description**

# The MAX14589E/MAX14594E high-density, double-pole/double-throw (DPDT) analog switches feature Beyond-the-Rails<sup>TM</sup> capability that allows signals from -5.5V to +5.5V to pass without distortion even when the power supply is below the signal range. The low R<sub>ON</sub> resistance (0.2 $\Omega$ ) makes the devices ideal for low-distortion switching, such as audio.

The MAX14594E has internal shunt switches that discharge the audio amplifier AC-coupling capacitance at the normally open (NO1 and NO2) terminals. This feature reduces click-and-pop sounds that occur when switching audio signals between precharged points.

The switches are fully specified to operate from a single +1.6V to +5.5V power supply. Because of the low supply current requirement,  $V_{\rm CCEN}$  can be provided by a GPIO. When the power is not applied, switches go to a high-impedance mode and all analog signal ports can withstand signals from -5.5V to +5.5V. The devices control the switches with a control bit, CB.

The MAX14589E/MAX14594E are available in a 1.2mm x 1.2mm, 0.4mm pitch, 9-bump wafer-level package (WLP), and operate over the -40°C to +85°C extended temperature range.

#### **Applications**

Smartphones

**Tablets** 

Portable Audio/Video Equipment

Portable Navigation Devices

#### **Benefits and Features**

- ♦ Distortion-Free Beyond-the-Rails Signaling
  - ♦ Negative Audio and Video Signal Capable

  - $\diamond$  On-Resistance 0.2 $\Omega$  (typ)

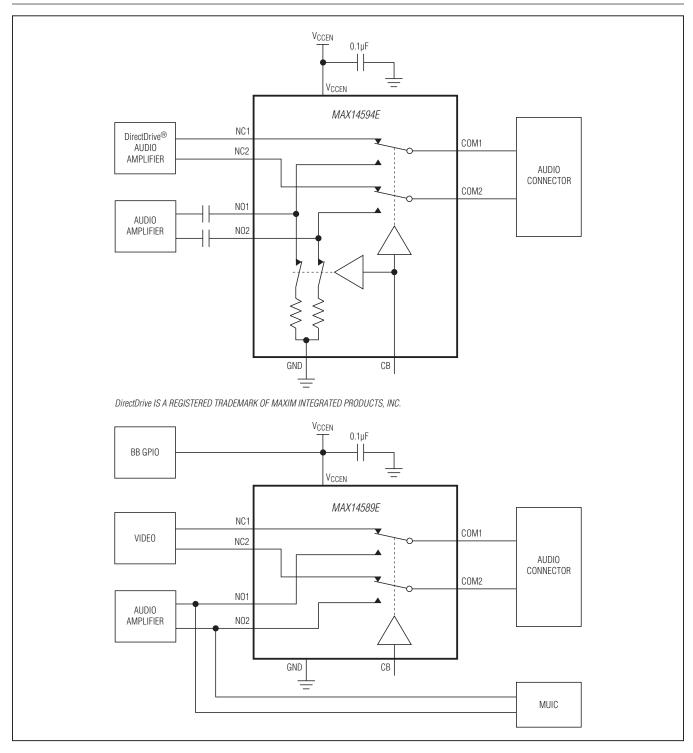
  - ♦ Click-and-Pop Suppression
- ♦ Smooth Switch Transition
  - ♦ Break-Before-Make Operation
- ♦ Low Supply Current 30µA (typ) at 1.6V
  - **♦** Can be Powered by a GPIO
  - ♦ High-Impedance Mode When V<sub>CCEN</sub> Not Applied
- ♦ ESD Protection on COM
- ♦ ESD Protection on NC\_ and NO\_
- ♦ Small Board Space
  - ♦ 9-Bump WLP (1.2mm x 1.2mm) Package
- ♦ -40°C to +85°C Operating Temperature Range

<u>Ordering Information/Selector Guide</u> appears at end of data sheet

For related parts and recommended products to use with this part, refer to www.maxim-ic.com/MAX14589E.related.

# High-Density, ±5V Capable DPDT Analog Switches

#### **Typical Application Circuits/Functional Diagrams**



# High-Density, ±5V Capable DPDT Analog Switches

#### **ABSOLUTE MAXIMUM RATINGS**

(All Voltages Referenced to GND.)	Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )
V <sub>CCEN</sub> , CB0.3V to +6V	WLP (derate 12mW/°C above +70°C)963.8mW
NC_, NO_, COM6V to +6V	Operating Temperature Range40°C to +85°C
Continuous Current NC_, NO_, COM±500mA	Junction Temperature+150°C
Peak Current NC_, NO_, COM_ (50% duty cycle) ±850mA	Storage Temperature Range65°C to +150°C
	Soldering Temperature (reflow)+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **PACKAGE THERMAL CHARACTERISTICS (Note 1)**

WLP

Junction-to-Ambient Thermal Resistance (θ<sub>JA</sub>) ......83°C/W

**Note 1:** Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <a href="https://www.maxim-ic.com/thermal-tutorial">www.maxim-ic.com/thermal-tutorial</a>.

#### **ELECTRICAL CHARACTERISTICS**

 $(V_{CCEN} = +1.6V \text{ to } +5.5V, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$  Typical values are at  $V_{CCEN} = +2.5V \text{ and } T_A = +25^{\circ}\text{C.})$  (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
POWER SUPPLY							
Power-Supply Range	V <sub>CCEN</sub>			1.6		5.5	V
PSRR		$R_{COM} = 32\Omega$ , $f = 20kHz$			80		dB
V Cumply Current		V <sub>CCEN</sub> = +1.60V, V <sub>CB</sub> = 0V or V <sub>CCEN</sub>			30	50	
vCCEN Supply Current	$V_{CCEN}$ Supply Current $V_{CCEN} = +4.2V$ , $V_{CCEN} = 0V$ or $V_{CCEN} = 0$			35	60	μΑ	
ANALOG SWITCH							
Analog Cignal Danga	V <sub>NC_</sub> ,	V <sub>CCEN</sub> > 1.6V		-5.5		+5.5	V
Analog Signal Range	V <sub>NO_</sub> , V <sub>COM_</sub>	$V_{CCEN} < 1.6V, R_S = 50\Omega$		-5.5		+5.5	
On-Resistance	R <sub>ON</sub>	OOW   OO	V <sub>CCEN</sub> = 2.5V		0.2	0.38	Ω
			V <sub>CCEN</sub> = 1.8V		0.25	0.43	
On-Resistance Match Between Channels	$\Delta R_{ON(NC)}$	V <sub>CCEN</sub> = 2.5V, V <sub>NC</sub> = 0V, I <sub>COM</sub> = 100mA, between same NC and NO channel (Note 4)			0.005	0.05	Ω
On-Resistance Flatness	R <sub>FLAT(ON)</sub>	V <sub>CCEN</sub> = 2.5V, I <sub>COM</sub> = 100mA, V <sub>COM</sub> = -5.5V to +5.5V (Notes 5, 6)			0.001	0.01	Ω
Shunt Switch Resistance	R <sub>SHUNT</sub>	I <sub>COM</sub> _ = 1mA, MAX14594E			500	1000	Ω
NC_ or NO_ Off-Leakage Current	INC_(OFF),	$V_{CCEN} = 2.5V$ ; open switch; $V_{NO}$ or $V_{NC} = -5.5V$ , $+5.5V$ ; $V_{COM} = +5.5V$ , $-5.5V$ , unconnected		-400		+400	nA
On-Leakage Ourient	I <sub>NO_(OFF)</sub>	$V_{CCEN}$ = 0V; $V_{NO}$ or $V_{NC}$ = 0V, +5.5V; $V_{COM}$ = +5.5V, 0V, unconnected		-400		+400	
COM_ Off-Leakage Current	I <sub>COM_(OFF)</sub>	V <sub>CCEN</sub> = 0V; V <sub>COM</sub> = +5.5V, 0V; V <sub>NO</sub> or V <sub>NC</sub> = 0V, +5.5V, unconnected		-400		+400	nA

# High-Density, ±5V Capable DPDT Analog Switches

#### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{CC} = +1.6V \text{ to } +5.5V, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$  Typical values are at  $V_{CC} = +2.5V \text{ and } T_A = +25^{\circ}\text{C}.)$  (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
COM_ On-Leakage Current	I <sub>COM_(ON)</sub>	V <sub>CCEN</sub> = 2.5V; switch closed; V <sub>COM</sub> = +5.5V, -5.5V; V <sub>NO</sub> or V <sub>NC</sub> = +5.5V, -5.5V, unconnected	-400 +4		+400	nA
DYNAMIC TIMING						
Turn-On Time	t <sub>ON</sub>	$V_{NO}$ or $V_{NC}$ = 0V, $R_L$ = 50 $\Omega$ , Figure 1a		5	10	ms
Turn-Off Time	t <sub>OFF</sub>	$V_{NO}$ or $V_{NC}$ = 0V, $R_L$ = 50 $\Omega$ , Figure 1a		1	2.25	ms
Break-Before-Make Time	t <sub>BBM</sub>	$R_L = 50\Omega$ , $V_{CCEN} = 3.3V$ , time for both NC_/NO_ switches are open during transition, Figure 1b (Note 5)	0 5 10		ms	
AUDIO PERFORMANCE						
Total Harmonic Distortion Plus Noise	THD+N	$f = 20$ Hz to $20$ kHz, $V_{COM} = 0.5$ V $_{P-P}$ , $R_S = R_L = 50\Omega$ , DC bias = 0V		0.001		%
Off-Isolation	$V_{\rm ISO}$	$R_S = R_L = 50\Omega$ , $V_{COM} = 0.5V_{P-P}$ , $f = 100kHz$ , $V_{CCEN} = 0V$ , DC bias = 0.25V, Figure 2		-60		dB
Crosstalk	V <sub>CT</sub>	$R_S = R_L = 50\Omega$ , $V_{COM} = 0.5V_{P-P}$ , $f = 100kHz$ , Figure 2 (Note 7)		-80		dB
-3dB Bandwidth	BW	$R_S = R_L = 50\Omega$ , Figure 2		200		MHz
NC_ or NO_ Off-Capacitance	C <sub>NC_(OFF)</sub> C <sub>NO_(OFF)</sub>	$V_{NC\_/NO_{-}} = 0.5V_{P-P}, f = 1MHz$		25		рF
COM_ On-Capacitance	C <sub>COM_(ON)</sub>	$V_{NC\_/NO\_} = 0.5V_{P-P}$ , $f = 1MHz$		50		pF
DIGITAL I/O (CB)						
Input Logic-High Voltage	V <sub>IH</sub>		1.4			V
Input Logic-Low Voltage	V <sub>IL</sub>				0.4	V
Input Leakage Current	I <sub>IN</sub>	V <sub>CB</sub> = 0V or V <sub>CCEN</sub>	-1		+1	μA
ESD PROTECTION						
		Human Body Model		±15		
COM1, COM2		IEC 61000-4-2 Air-Gap Discharge		±10		kV
		IEC 61000-4-2 Contact Discharge		±8		
NO_, NC_		Human Body Model		±15		kV
All Other Pins		Human Body Model		±2		kV

- Note 2: All specifications are 100% production tested at  $T_A = +25$ °C, unless otherwise noted. Specifications are over -40°C to +85°C and are guaranteed by design.

  Note 3: The same limits apply for  $V_{COM}$  = -5.5V to +5.5V and are guaranteed by design.

  Note 4:  $\Delta R_{ON(MAX)} = IR_{ON(CH1)} - R_{ON(CH2)}I$ .

- **Note 5:** Guaranteed by design; not production tested.
- Note 6: Flatness is defined as the difference between the maximum and minimum value of on-resistance, as measured over specified analog signal ranges.
- Note 7: Between two switches.

# High-Density, ±5V Capable DPDT Analog Switches

#### **Timing Diagrams**

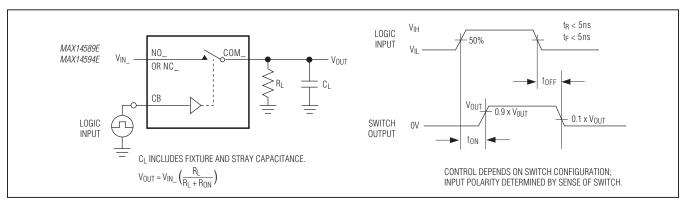


Figure 1a. Switching Time

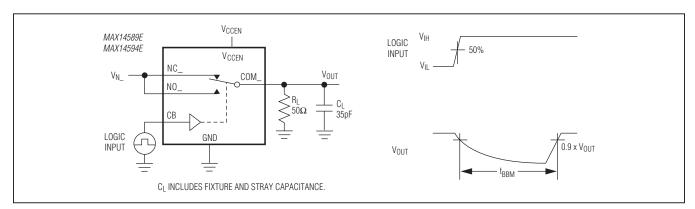


Figure 1b. Break-Before-Make Interval

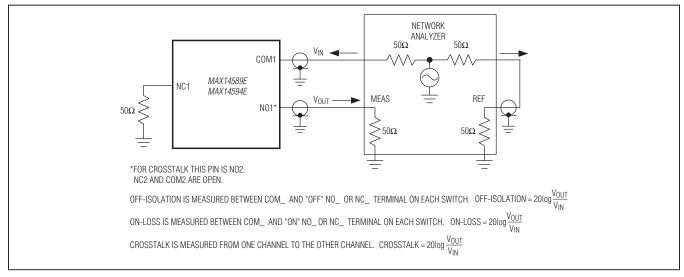
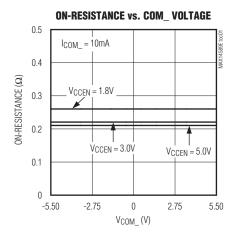


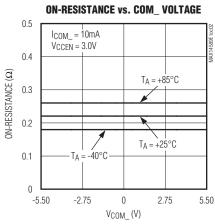
Figure 2. On-Loss, Off-Isolation, and Crosstalk

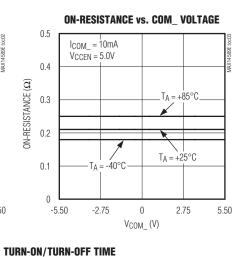
# High-Density, ±5V Capable DPDT Analog Switches

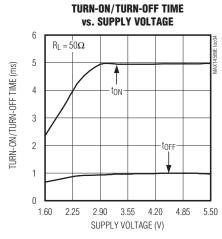
#### **Typical Operating Characteristics**

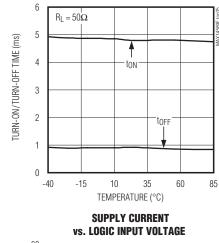
 $(V_{CCEN} = +2.5V, T_A = +25^{\circ}C, unless otherwise noted.)$ 



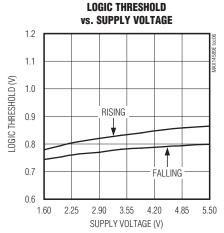


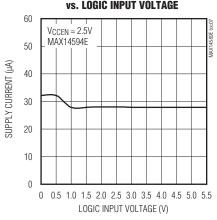






vs. TEMPERATURE

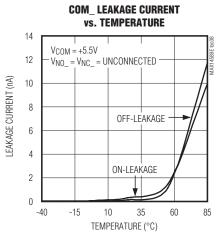


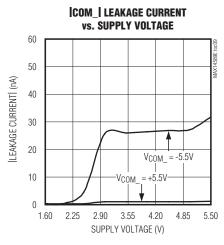


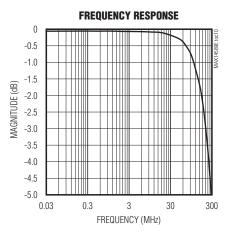
# High-Density, ±5V Capable DPDT Analog Switches

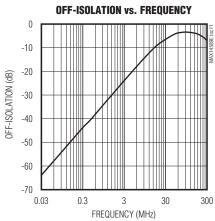
#### **Typical Operating Characteristics (continued)**

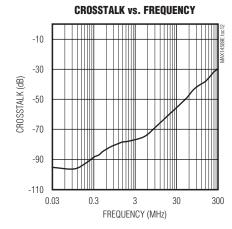
 $(V_{CCEN} = +2.5V, T_A = +25^{\circ}C, unless otherwise noted.)$ 

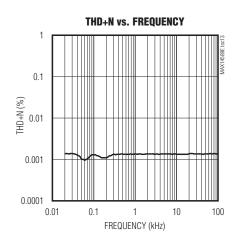


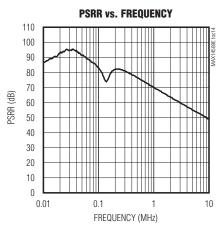






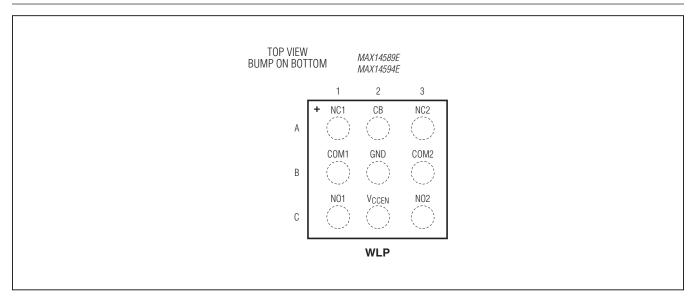






# High-Density, ±5V Capable DPDT Analog Switches

#### **Bump Configuration**



# **Bump Description**

BUMP	NAME	FUNCTION
A1	NC1	Normally Closed Terminal for Switch 1
A2	СВ	Digital Control Input. Drive CB low to connect COM_ to NC Drive CB high to connect COM_ to NO
A3	NC2	Normally Closed Terminal for Switch 2
B1	COM1	Common Terminal for Switch 1
B2	GND	Ground
В3	COM2	Common Terminal for Switch 2
C1	NO1	Normally Open Terminal for Switch 1
C2	V <sub>CCEN</sub>	Positive Supply Voltage Input. Bypass V <sub>CCEN</sub> to GND with a 0.1µF capacitor as close as possible to the device.
C3	NO2	Normally Open Terminal for Switch 2

# High-Density, ±5V Capable DPDT Analog Switches

#### **Detailed Description**

The MAX14589E/MAX14594E are low on-resistance and high ESD-protected DPDT switches that operate from a +1.6V to +5.5V supply and are designed to multiplex AC-coupled analog signals. These switches feature the low on-resistance (R $_{\rm ON}$ ) necessary for high-performance switching applications. The Beyond-the-Rails signal capability of the analog channel allows signals below ground and above  $V_{\rm CCEN}$  to pass through without distortion.

#### **Analog Signal Levels**

The devices are bidirectional, allowing NO\_, NC\_, and COM\_ to be configured as either inputs or outputs. The topology of the internal switches allows the signal to drop below ground without the need of an external negative voltage supply. **Note:** The devices can withstand analog signal levels of -5.5V to +5.5V when the device is not powered.

#### **Digital Control Input**

The devices provide a single-bit control logic input, CB. CB controls the switch position, as shown in the <u>Typical</u> Application Circuits/Functional Diagrams.

# Click-and-Pop Suppression (MAX14594E Only)

The  $500\Omega$  shunt resistors automatically discharge any capacitance at both NO\_ terminals when they are not connected to COM\_. This reduces audio click-and-pop

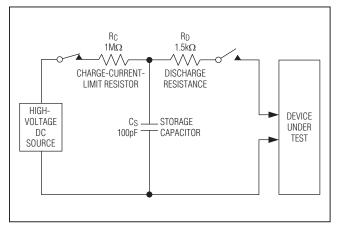


Figure 3. Human Body ESD Test Model

sounds that might occur when switching between capacitively coupled audio sources.

The shunt resistors are controlled by CB. When CB is low, NC\_ is connected to COM\_ and NO\_ is connected to the shunt resistors. When CB is high, NO\_ is connected to COM\_ and the shunt resistors are unconnected.

#### **Applications Information**

#### **Extended ESD Protection**

ESD-protection structures are incorporated on all pins to protect against electrostatic discharges up to ±2kV (HBM) encountered during handling and assembly. COM1 and COM2 are further protected against ESD up to ±15kV (HBM), ±10kV (Air-Gap Discharge), and ±8kV (Contact Discharge) without damage. NO\_ and NC\_ are further protected against ESD up to ±15kV (HBM) without damage. The ESD structures withstand high ESD both in normal operation and when the device is powered down. After an ESD event, the devices continue to function without latchup.

#### **ESD Test Conditions**

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report that documents test methodology and test results.

#### Human Body Model

Figure 3 shows the Human Body Model. Figure 4 shows the current waveform it generates when discharged into a low impedance. This model consists of a 100pF capacitor charged to the ESD voltage of interest that is then discharged into the device through a  $1.5 \mathrm{k}\Omega$  resistor.

#### IEC 61000-4-2

The IEC 61000-4-2 standard covers ESD testing and performance of finished equipment. It does not specifically refer to integrated circuits. The major difference between tests done using the HBM and IEC 61000-4-2 is higher peak current in IEC 61000-4-2, because series resistance is lower in the IEC 61000-4-2 model. Hence, the ESD withstand voltage measured to IEC 61000-4-2 is generally lower than that measured using the HBM. Figure 4 shows the IEC 61000-4-2 model and Figure 5 shows the current waveform for the ±8kV, IEC 61000-4-2, Level 4, ESD Contact-Discharge Method.

# **High-Density, ±5V Capable DPDT Analog Switches**

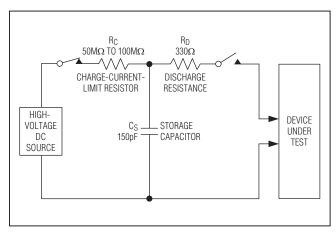


Figure 4. IEC 61000-4-2 ESD Test Model

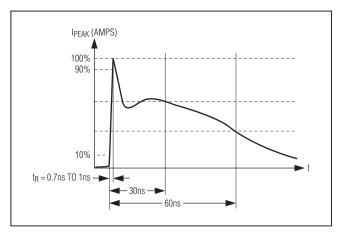


Figure 5. IEC 61000-4-2 ESD Generator Current Waveform

#### **Chip Information**

PROCESS: BICMOS

## Package Information

For the latest package outline information and land patterns (footprints), go to <a href="https://www.maxim-ic.com/packages">www.maxim-ic.com/packages</a>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE	PACKAGE	OUTLINE	LAND
TYPE	CODE	NO.	PATTERN NO.
9 WLP	W91B1+7	<u>21-0459</u>	Refer to Application Note 1891

#### Ordering Information/ Selector Guide

PART	PIN- PACKAGE	TOP MARK	SHUNT RESISTOR	
MAX14589EEWL+T	9 WLP	AJA	No	
MAX14594EEWL+T	9 WLP	AJB	Yes	

**Note:** All devices are specified over the -40°C to +85°C temperature range.

<sup>+</sup>Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

# High-Density, ±5V Capable DPDT Analog Switches

#### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	6/12	Initial release	_

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time. The parametric values (min and max limits) shown in the Electrical Characteristics table are guaranteed. Other parametric values quoted in this data sheet are provided for guidance.